## **MOSFET** – Power, P-Channel, SOT-23

## -20 V, -1.3 A

These miniature surface mount MOSFETs low RDS(on) assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low R<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- NVTR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free and Halide-Free Packages are Available

## **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	-20	V
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	±12	V
Drain Current  - Continuous @ $T_A$ = 25°C  - Pulsed Drain Current ( $t_p \le 10 \mu s$ )	I <sub>D</sub> I <sub>DM</sub>	-1.3 -4.0	A A
Total Power Dissipation @ T <sub>A</sub> = 25°C	$P_{D}$	400	mW
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to 150	°C
Thermal Resistance - Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	TL	260	°C

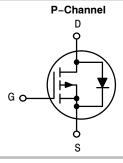
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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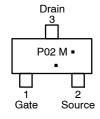
V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> Max	I <sub>D</sub> Max
–20 V	220 mΩ @ -4.5 V	–1.3 A



### **MARKING DIAGRAM & PIN ASSIGNMENT**



SOT-23 **CASE 318** STYLE 21



P02 = Specific Device Code

= Date Code\* M

= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTR1P02LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel
NTR1P02LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel
NVTR01P02LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C \ unless \ otherwise \ noted)$

Parameter	Test Condition	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•		•		•
Drain-to-Source Breakdown Voltage	$(V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A})$	V <sub>(BR)DSS</sub>	-20			V
Zero Gate Voltage Drain Current	$(V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V})$ $(V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V},$ $T_{J} = 125^{\circ}\text{C})$	I <sub>DSS</sub>			-1.0 -10	μΑ
Gate-Body Leakage Current	$(V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V})$	I <sub>GSS</sub>			±100	nA
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage	$(V_{DS} = V_{GS}, I_{D} = -250 \mu A)$	$V_{GS(th)}$	-0.7	-1.0	-1.25	V
Static Drain-to-Source On-Resistance	$(V_{GS} = -4.5 \text{ V}, I_D = -0.75 \text{ A})$ $(V_{GS} = -2.5 \text{ V}, I_D = -0.5 \text{ A})$	r <sub>DS(on)</sub>		0.140 0.200	0.22 0.35	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	$(V_{DS} = -5.0 \text{ V})$	C <sub>iss</sub>		225		pF
Output Capacitance	$(V_{DS} = -5.0 \text{ V})$	C <sub>oss</sub>		130		
Transfer Capacitance	$(V_{DS} = -5.0 \text{ V})$	C <sub>rss</sub>		55		
SWITCHING CHARACTERISTICS	(Note 2)					
Turn-On Delay Time		t <sub>d(on)</sub>		7.0		ns
Rise Time	$(V_{GS} = -4.5 \text{ V}, V_{DD} = -5.0 \text{ V}, I_{D} = -1.0 \text{ A}, R_{I} = 5.0 \Omega,$	t <sub>r</sub>		15		
Turn-Off Delay Time	$R_G = 6.0 \Omega$	t <sub>d(off)</sub>		18		
Fall Time		t <sub>f</sub>		9		
Total Gate Charge	$(V_{DS} = -16 \text{ V}, I_{D} = -1.5 \text{ A}, V_{GS} = -4.5 \text{ V})$	Q <sub>T</sub>		3.1		nC
SOURCE-DRAIN DIODE CHARAC	TERISTICS					-
Continuous Current		I <sub>S</sub>			-0.6	Α
Pulsed Current		I <sub>SM</sub>			-0.75	
Forward Voltage (Note 2)	$(V_{GS} = 0 \text{ V}, I_S = -0.6 \text{ A})$	$V_{SD}$			-1.0	V
Reverse Recovery Time		t <sub>rr</sub>		16		ns
	$(I_S = -1.0 \text{ A}, V_{GS} = 0 \text{ V}, \\ dI_S/dt = 100 \text{ A}/\mu\text{s})$	ta		11		
	a.g, a , , , , , , ,	t <sub>b</sub>		5.5		
Reverse Recovery Stored Charge		$Q_{RR}$		8.5		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width  $\leq 300~\mu s$ , Duty Cycle  $\leq 2\%$ .

2. Switching characteristics are independent of operating junction temperature.

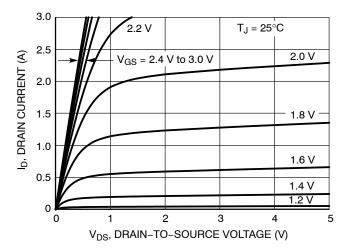


Figure 1. On-Region Characteristics

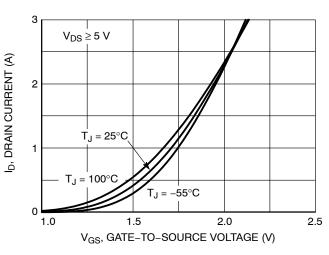


Figure 2. Transfer Characteristics

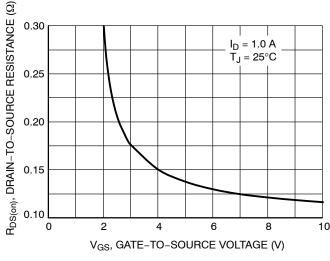


Figure 3. On-Resistance vs. Gate-to-Source Voltage

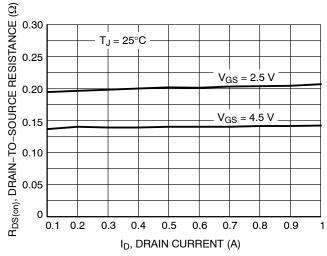


Figure 4. On–Resistance vs. Drain Current and Gate Voltage

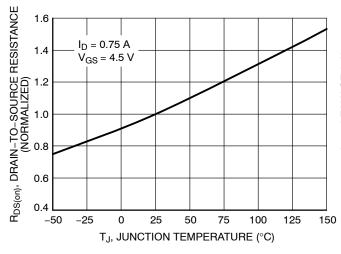


Figure 5. On–Resistance Variation with Temperature

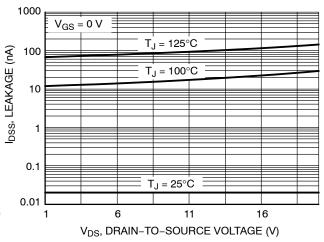


Figure 6. Drain-to-Source Leakage Current vs. Voltage

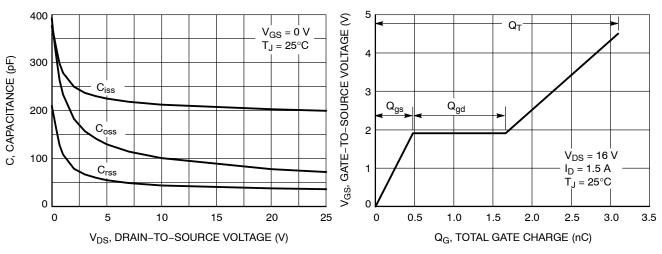


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

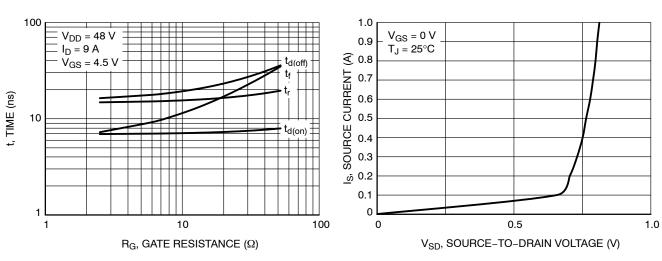


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

Figure 10. Diode Forward Voltage vs. Current

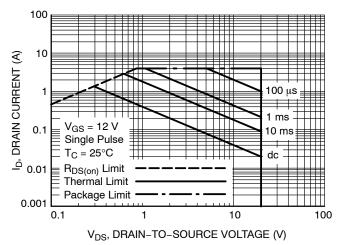


Figure 11. Maximum Rated Forward Biased Safe Operating Area



SOT-23 (TO-236) CASE 318-08 **ISSUE AS** 

**DATE 30 JAN 2018** 

# SCALE 4:1 D - 3X b

**TOP VIEW** 







#### **RECOMMENDED SOLDERING FOOTPRINT**



DIMENSIONS: MILLIMETERS

#### NOTES:

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
  MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,

	PROT	RUSIONS, OR GATE BURRS.	
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	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

## **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE
OT (1 F O			

SOT-23 (TO-236)

STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
<ol><li>ANODE</li></ol>	<ol><li>SOURCE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	2. DRAIN	2. GATE
<ol><li>CATHODE</li></ol>	3. GATE	<ol><li>CATHODE-ANODE</li></ol>	<ol><li>ANODE</li></ol>	3. GATE	<ol><li>ANODE</li></ol>

STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	2. ANODE	<ol><li>CATHODE</li></ol>	2. ANODE	<ol><li>ANODE</li></ol>
<ol><li>ANODE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>CATHODE</li></ol>	<ol><li>ANODE</li></ol>	<ol><li>CATHODE-ANOD</li></ol>	E 3. GATE

STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
<ol><li>SOURCE</li></ol>	<ol><li>OUTPUT</li></ol>	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3 DRAIN	3 INPLIT	3 CATHODE	3. SOURCE	3. GATE	<ol><li>NO CONNECTION</li></ol>

STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE	
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